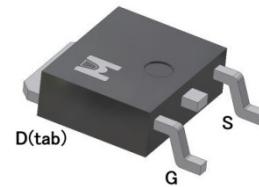
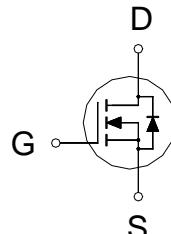


N-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

| | |
|--------------------------|-----|
| BV _{DSS} | 60V |
| R _{DSON} (MAX.) | 6mΩ |
| I _D | 68A |



UIS, R_G 100% Tested

Pb-Free Lead Plating & Halogen Free



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | | SYMBOL | LIMITS | UNIT |
|--|---------------------------|-----------------------------------|------------|------|
| Gate-Source Voltage | | V _{GS} | ±20 | V |
| Continuous Drain Current | T _C = 25 °C | I _D | 68 | A |
| | T _C = 100 °C | | 40 | |
| Pulsed Drain Current ^{1,3} | | I _{DM} | 170 | |
| Avalanche Current | | I _{AS} | 68 | |
| Avalanche Energy | L = 0.1mH, ID=68A, RG=25Ω | E _{AS} | 230 | mJ |
| Repetitive Avalanche Energy ² | L = 0.05mH | E _{AR} | 115 | |
| Power Dissipation | T _C = 25 °C | P _D | 50 | W |
| | T _C = 100 °C | | 20 | |
| Operating Junction & Storage Temperature Range | | T _j , T _{stg} | -55 to 150 | °C |

100% UIS testing in condition of V_D=30V, L=0.1mH, V_G=10V, I_L=50A, Rated V_{DS}=60V N-CH

THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNIT |
|---------------------|------------------|---------|---------|--------|
| Junction-to-Case | R _{θJC} | 2.5 | 2.5 | °C / W |
| Junction-to-Ambient | R _{θJA} | | 75 | |

¹Pulse width limited by maximum junction temperature.

²Duty cycle ≤ 1%

³Pulsed drain current rating is package limited.

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|---|-----------------------------|--|--------|------|-----------|------------------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{GS} = 0V, I_D = 250\mu\text{A}$ | 60 | | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 2 | 3 | 4 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 48V, V_{GS} = 0V$ | | | 1 | μA |
| | | $V_{DS} = 40V, V_{GS} = 0V, T_J = 125^\circ\text{C}$ | | | 25 | |
| On-State Drain Current ¹ | $I_{D(\text{ON})}$ | $V_{DS} = 10V, V_{GS} = 10V$ | 68 | | | A |
| Drain-Source On-State Resistance ¹ | $R_{DS(\text{ON})}$ | $V_{GS} = 10V, I_D = 30A$ | | 5.0 | 6.0 | $\text{m}\Omega$ |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 5V, I_D = 30A$ | | 52 | | S |
| DYNAMIC | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 25V, f = 1\text{MHz}$ | | 3057 | | pF |
| Output Capacitance | C_{oss} | | | 441 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 112 | | |
| Gate Resistance | R_g | $V_{GS} = 15\text{mV}, V_{DS} = 0V, f = 1\text{MHz}$ | | 2.7 | | Ω |
| Total Gate Charge ^{1,2} | Q_g | $V_{DS} = 30V, V_{GS} = 10V, I_D = 30A$ | | 40 | | nC |
| Gate-Source Charge ^{1,2} | Q_{gs} | | | 17 | | |
| Gate-Drain Charge ^{1,2} | Q_{gd} | | | 11 | | |
| Turn-On Delay Time ^{1,2} | $t_{d(\text{on})}$ | $V_{DS} = 30V, I_D = 1A, V_{GS} = 10V, R_{GS} = 6\Omega$ | | 20 | | nS |
| Rise Time ^{1,2} | t_r | | | 75 | | |
| Turn-Off Delay Time ^{1,2} | $t_{d(\text{off})}$ | | | 110 | | |
| Fall Time ^{1,2} | t_f | | | 85 | | |
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_C = 25^\circ\text{C}$) | | | | | | |
| Continuous Current | I_S | | | | 68 | A |
| Pulsed Current ³ | I_{SM} | | | | 170 | |
| Forward Voltage ¹ | V_{SD} | $I_F = 20A, V_{GS} = 0V$ | | | 1.3 | V |
| Reverse Recovery Time | t_{rr} | $I_F = 25A, dI_F/dt = 100A/\mu\text{s}$ | | 35 | | nS |
| Reverse Recovery Charge | Q_{rr} | | | | 160 | nC |

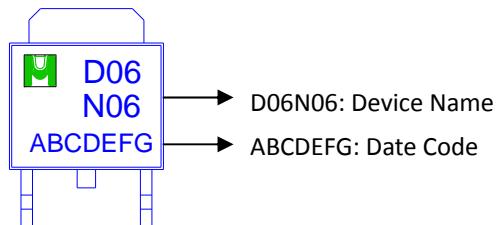
¹Pulse test : Pulse Width $\leq 300\ \mu\text{sec}$, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

³Pulse width limited by maximum junction temperature.

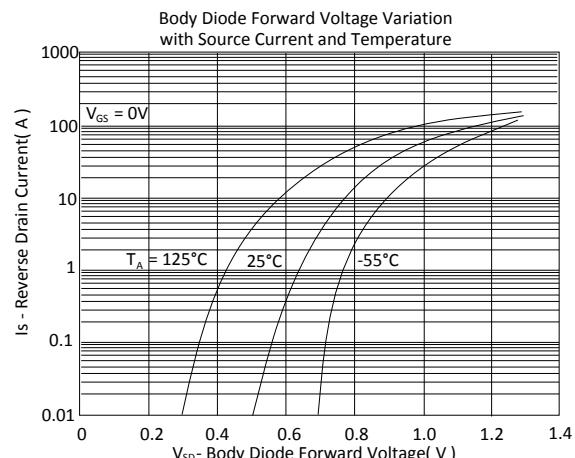
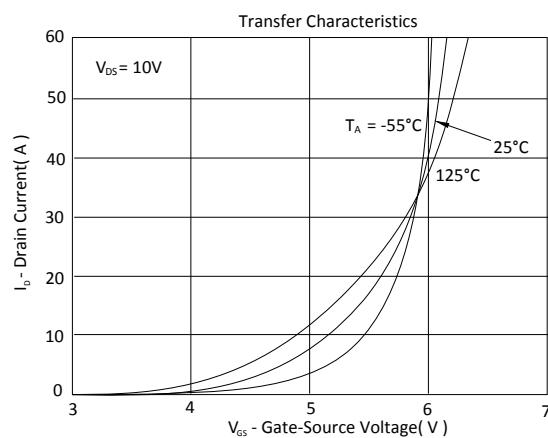
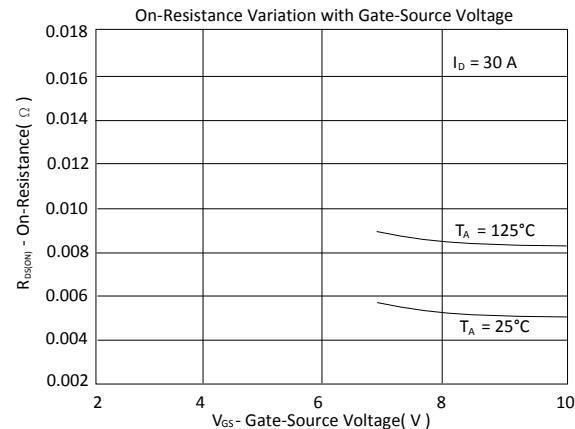
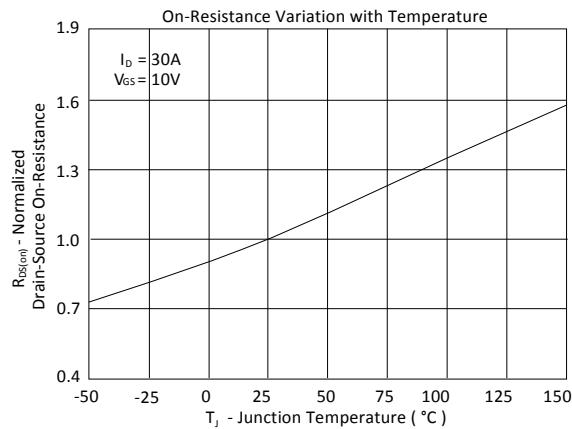
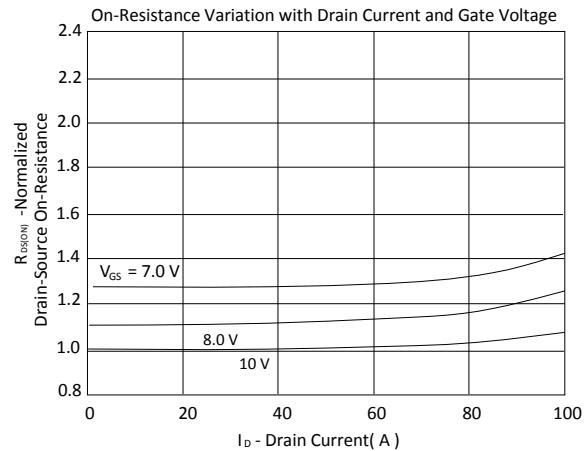
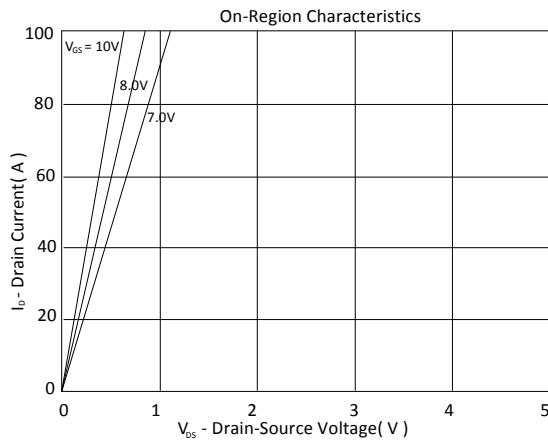
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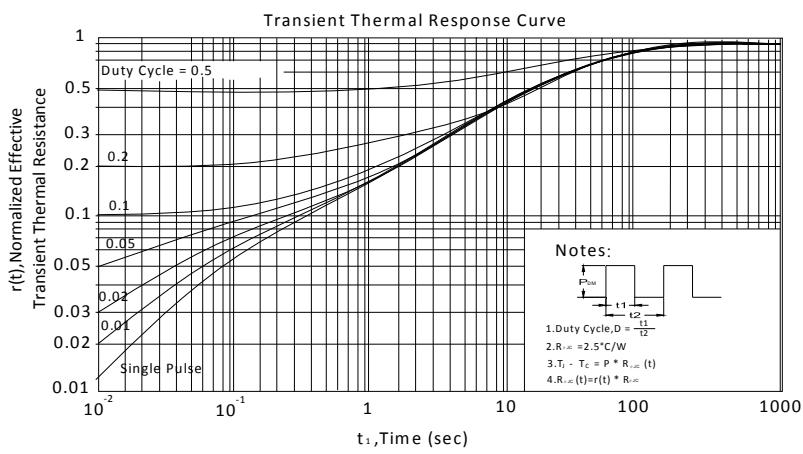
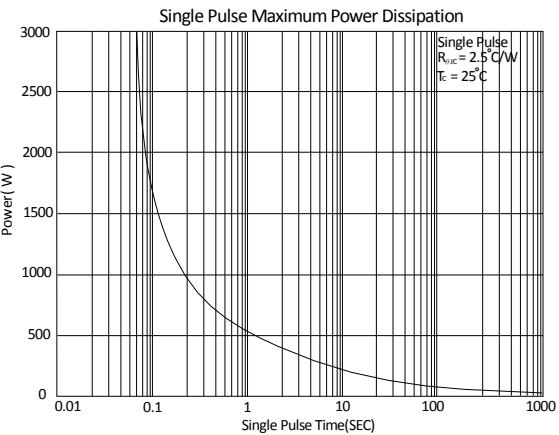
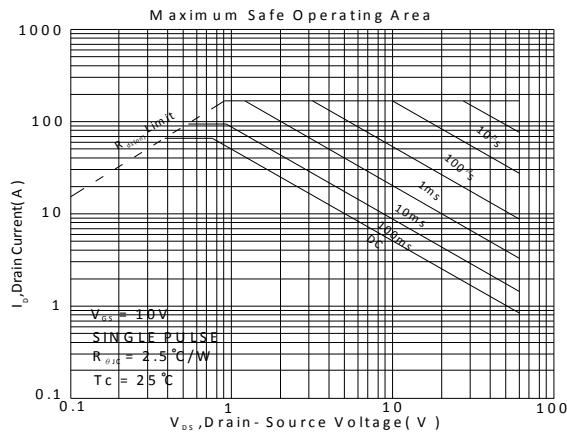
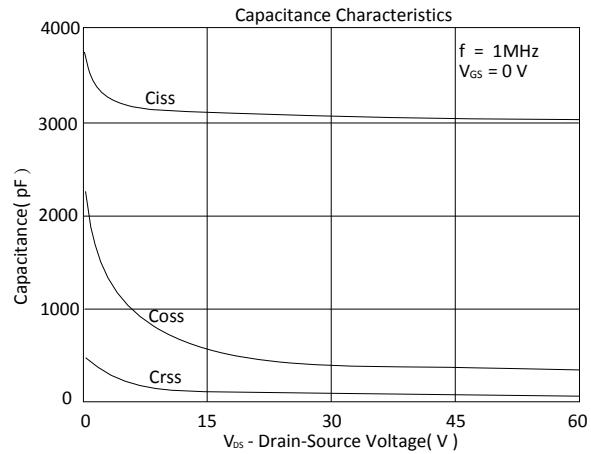
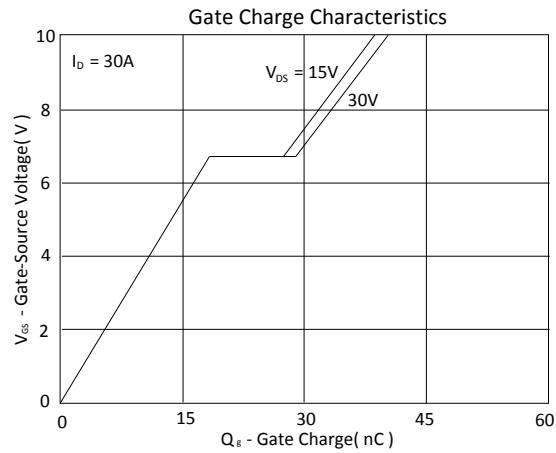
Device Name: EMD06N06A for TO-252



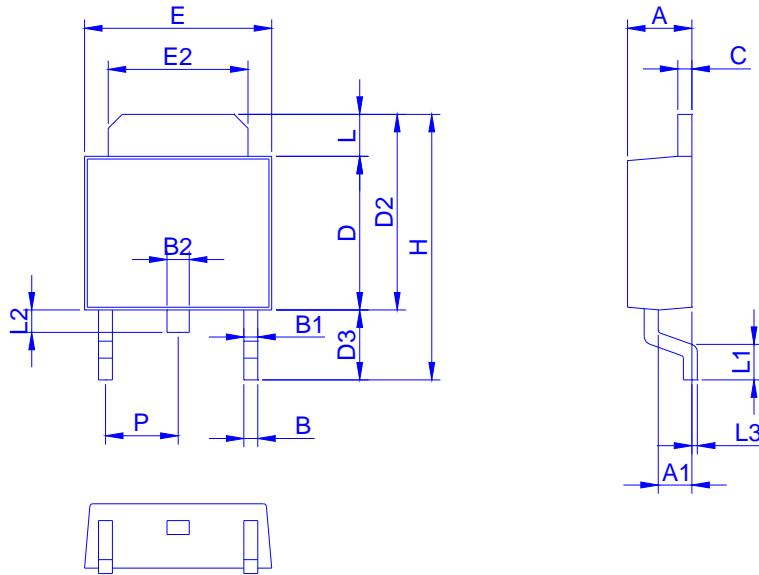


TYPICAL CHARACTERISTICS





Outline Drawing



Dimension in mm

| Dimension | A | A1 | B | B1 | B2 | C | D | D2 | D3 | E | E2 | H | L | L1 | L2 | L3 | P |
|-----------|------|------|------|------|------|------|------|------|------|------|------|-------|------|------|------|------|------|
| Min. | 2.10 | 0.95 | 0.30 | 0.40 | 0.60 | 0.40 | 5.30 | 6.70 | 2.20 | 6.40 | 4.80 | 9.20 | 0.89 | 0.90 | 0.50 | 0.00 | 2.10 |
| Max. | 2.50 | 1.30 | 0.85 | 0.94 | 1.00 | 0.60 | 6.20 | 7.30 | 3.00 | 6.70 | 5.45 | 10.15 | 1.70 | 1.65 | 1.10 | 0.30 | 2.50 |

Footprint

